TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

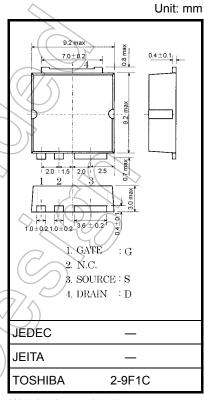
# 2SK3466

#### **Chopper Regulator Applications**

- Low drain-source ON-resistance: R<sub>DS</sub> (ON) = 1.35 Ω (typ.)
- High forward transfer admittance:  $|Y_{fS}| = 4.0 \text{ S (typ.)}$
- Low leakage current:  $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 500 \text{ V)}$
- Enhancement mode:  $V_{th}$  = 2.0 to 4.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			$V_{DSS}$	500	$(\nearrow \ \land)$
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )			$V_{DGR}$	500	V
Gate-source voltage			$V_{GSS}$	±30	y
Drain current	DC	(Note 1)	ΙD	5	⇒ <sub>A</sub>
	Pulse	(Note 1)	$I_{DP}$	20	× A
Drain power dissipation (Tc = 25°C)			$P_{D}$	50	W
Single pulse avalanche energy (Note 2)			EAS	180	mJ
Avalanche current			IAR	5	A
Repetitive avalanche energy (Note 3)			EAR	)) 5	mJ
Channel temperature			Tch	150	∕\°C
Storage temperature range			T <sub>stg</sub>	−55 to 150 °C	



Weight: 0.74 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

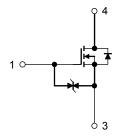
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th</sub> (ch-c)	2.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 12.2 mH,  $R_G = 25 \Omega$ ,  $I_{AR} = 5 \text{ A}$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



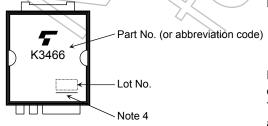
## **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-OFF cu	ırrent	I <sub>DSS</sub>	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0 V	_	_	100	μA
Drain-source bre	akdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	500	_		٧
Gate threshold vo	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	_	4.0	٧
Drain-source ON	resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A	17	1.35	1.50	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 5 A	2.5	4.0	_	S
Input capacitance		C <sub>iss</sub>		$\mathcal{C}$	780	_	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		60	_	pF
Output capacitance		C <sub>oss</sub>		<sup>7</sup> —	200	_	
Switching time	Rise time	t <sub>r</sub>	10 V	_	12	<i> </i> //	
	Turn-ON time	t <sub>on</sub>	V <sub>GS</sub> 0 V R <sub>L</sub> = 90 Ω	-(	25	> _	
	Fall time	t <sub>f</sub>	15 Ω V <sub>DD</sub> ≈ 225 V	7	15	_	ns
	Turn-OFF time	t <sub>off</sub>	Duty ≤ 1%, t <sub>w</sub> = 10 μs		60	_	
Total gate charge (gate-source plus		Qg		)_	17		
Gate-source charge		Qgs	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$	_	11	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>		_	6	_	

# Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	$(7/\land -$	_	_	5	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	<u> </u>	_	_	20	Α
Forward voltage (diode)	$V_{DSF}$	I <sub>DR</sub> = 5 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$	_	1400	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A/μs	_	9	_	μC

## Marking

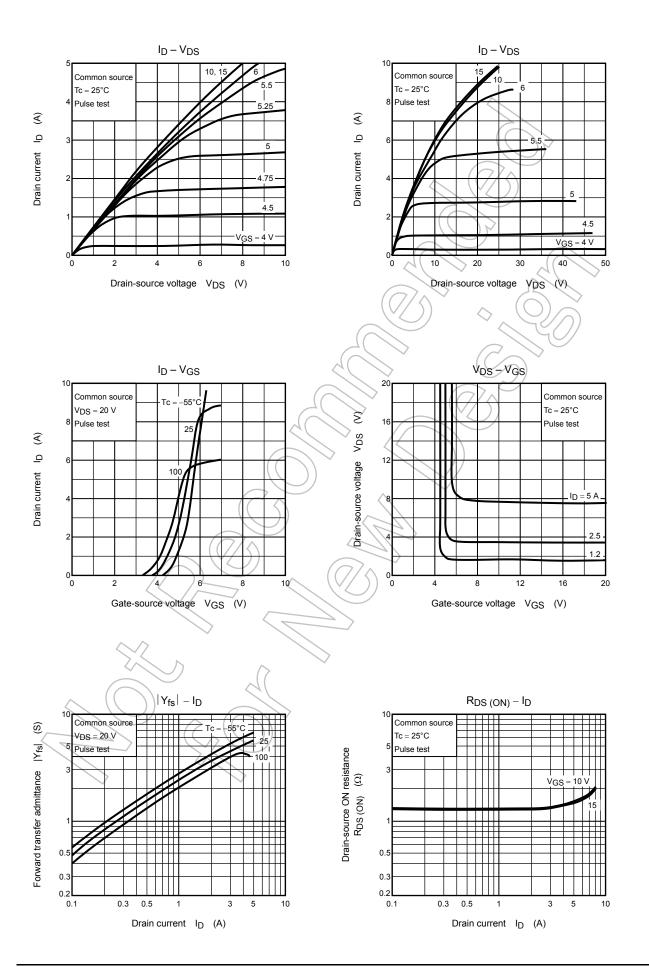


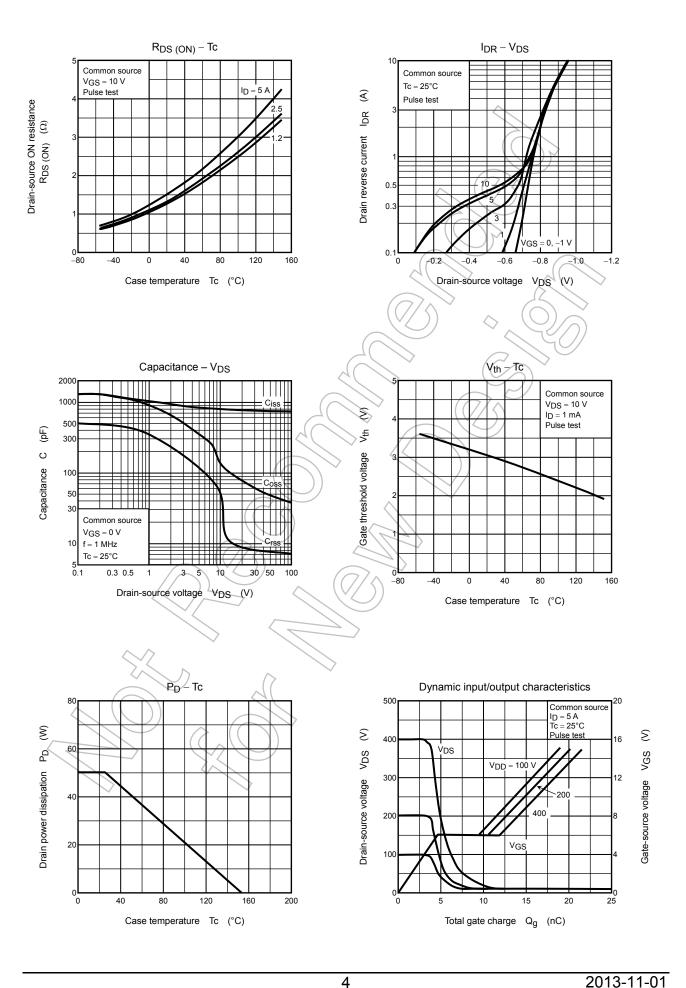
Note 4: A line under a Lot No. identifies the indication of product Labels.

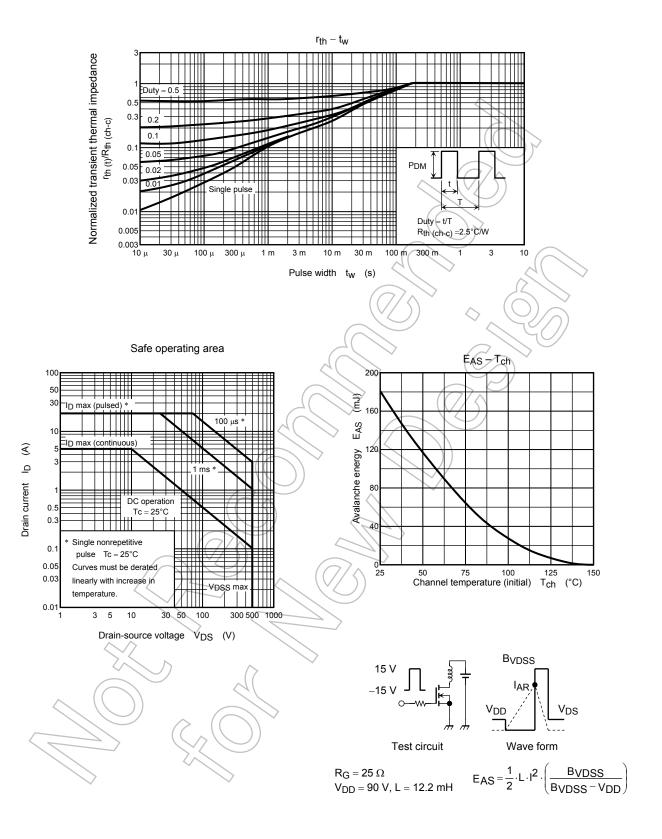
Not underlined: [[Pb]]/INCLUDES > MCV

 $\label{thm:compatible} \mbox{Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$ 

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.







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